

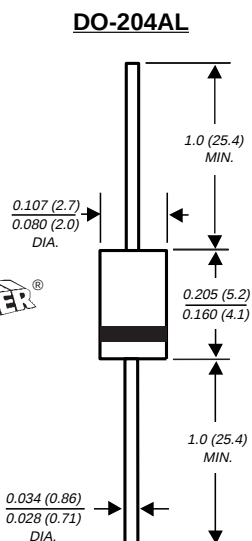
EGP10A THRU EGP10G

GLASS PASSIVATED FAST EFFICIENT RECTIFIER

Reverse Voltage - 50 to 400 Volts Forward Current - 1.0 Ampere

PATENTED *

SUPERRECTIFIER®



Dimensions in inches and (millimeters)

* Glass Encapsulation technique is covered by
Patent No. 3,996,602, brazed-lead assembly to Patent No. 3,930,306

FEATURES

- ♦ Plastic package has Underwriters Laboratories Flammability Classification 94V-0
- ♦ Glass passivated cavity-free junction
- ♦ Superfast recovery time for high efficiency
- ♦ Low forward voltage, high current capability
- ♦ Low leakage current
- ♦ High surge current capability
- ♦ High temperature metallurgically bonded construction
- ♦ High temperature soldering guaranteed:
300°C/10 seconds, 0.375" (9.5mm) lead length,
5 lbs. (2.3kg) tension



MECHANICAL DATA

Case: JEDEC DO-204AL molded plastic over glass body

Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight: 0.012 ounce, 0.3 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	SYMBOLS	EGP 10A	EGP 10B	EGP 10C	EGP 10D	EGP 10F	EGP 10G	UNITS
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	150	200	300	400	Volts
Maximum RMS voltage	V _{RMS}	35	70	105	140	210	280	Volts
Maximum DC blocking voltage	V _{DC}	50	100	150	200	300	400	Volts
Maximum average forward rectified current 0.375" (9.5mm) lead length at T _A =55°C	I _(AV)	1.0						Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load	I _{FSM}	30.0						Amps
Maximum instantaneous forward voltage at 1.0A	V _F	0.95				1.25		Volts
Maximum DC reverse current T _A =25°C at rated DC blocking voltage T _A =125°C	I _R	5.0 100						μA
Maximum reverse recovery time (NOTE 1)	t _{rr}	50.0						ns
Typical junction capacitance (NOTE 2)	C _J	22.0				15.0		pF
Typical thermal resistance (NOTE 3)	R _{θJA}	50.0						°C/W
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +150						°C

NOTES:

(1) Reverse recovery test conditions: I_F=0.5A, I_R=1.0A, I_{rr}=0.25A

(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts

(3) Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

RATINGS AND CHARACTERISTICS CURVES EGP10A THRU EGP10G

FIG. 1 - MAXIMUM FORWARD CURRENT DERATING CURVE

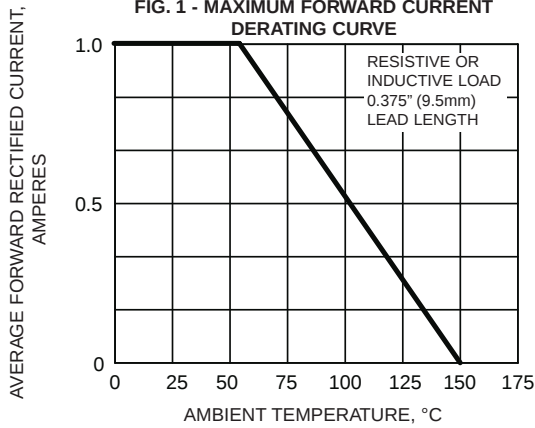


FIG. 2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

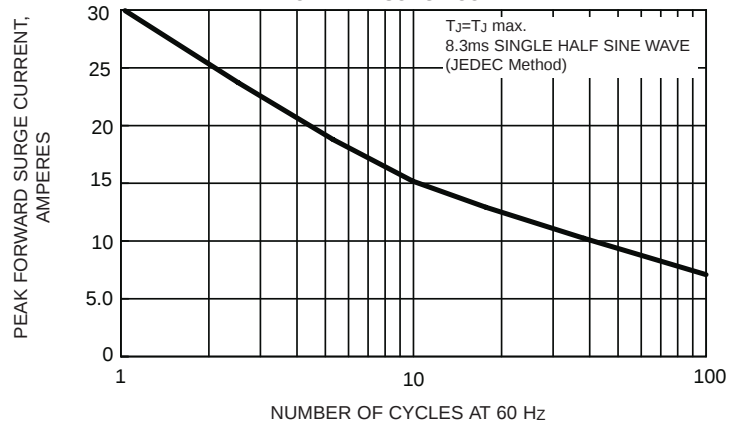


FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

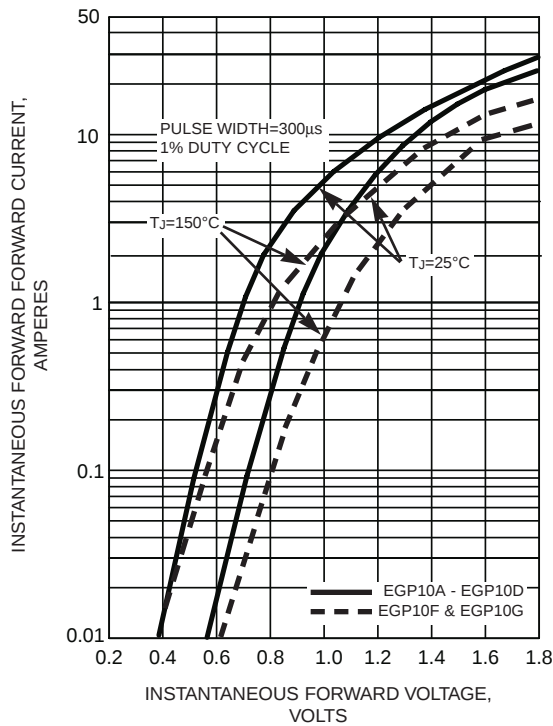


FIG. 4 - TYPICAL REVERSE CHARACTERISTICS

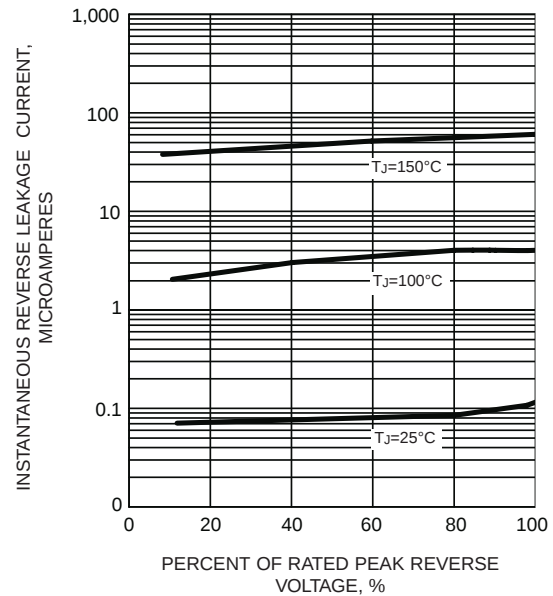


FIG. 5 - TYPICAL JUNCTION CAPACITANCE

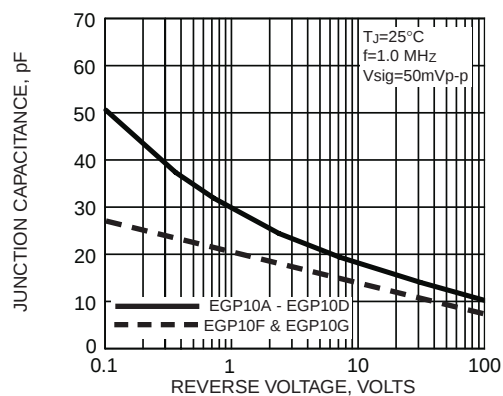


FIG. 6 - TYPICAL TRANSIENT THERMAL IMPEDANCE

